Ref #	Hits	Search Query	DBs	Default Operator	Plurais	Time Stamp
L3	145005	silicon near substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/02 13:48
L2	59	relax\$2 near3 graded near buffer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/02 13:49
L3	605	(GeSi or SiGe) same graded	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/02 13:49
L4	361	I1 and I3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/02 13:50
L5	272	I4 and crystal\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/02 13:50